OPB610, OPB611, OPB620, OPB621

Features:

- Non-contact switching
- Printed circuit board mounting
- Enhanced signal to noise ratio
- PIN photodiode sensor for high speed (OPB611, OPB621) .
- Lead centers: 0.275: (OPB61) / 0.320" (OPB62)

Electronics

Aperture

Emitter / Sensor

0.06" / 0.06"

Lead Length /

Spacing

0.100" / 0.275"

0.100" / 0.320"

Slot Width

Depth

0.150" / 0.240"

0.190" / 0.285"

Description:

The OPB610 and OPB620 slotted optical switches consist of an infrared emitting diode and an NPN silicon phototransistor with an enhanced low current roll-off to improve contrast ratio and immunity to background irradiance.

The OPB611, OPB621 slotted optical switch consists of an infrared emitting diode and a PIN photodiode with a polysulfone housing that is opaque to visible light, but transmissive to infrared. The low t_r/t_f of the PIN photodiode is ideal for highspeed operation. The sensitivity to ambient radiation is minimized.

Custom electrical, wire and cabling and connectors are available. Contact your local representative or OPTEK for more information. Ordering Information

LED Peak

Wavelength

890 nm

Sensor

Rbe Transistor

Diode

Rbe Transistor

Part

Number

OPB610

OPB611

OPB620

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety •
- End of travel sensor



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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OPB610, OPB611, OPB620, OPB621

Electrical Specifications

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage and Operating Temperature Range	-40°C to +100° C
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] $^{(1)}$	260° C
nput Diode	
Forward DC Current	50 mA
Peak Forward Current (1 μs pulse width, 300 pps)	3 A
Reverse DC Voltage	3 V
Power Dissipation ⁽²⁾	100 mW
Dutput Photodiode (OPB621)	
Reverse Breakdown Voltage	60 V
Power Dissipation	100 mW
Dutput Phototransistor (OPB610, OPB620)	
Collector-Emitter Voltage	24 V
Emitter-Reverse Current	10 mA
Collector DC Current	30 mA
Power Dissipation ⁽³⁾	200 mW



OPB610, OPB611, OPB620, OPB621

Electrical Specifications

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
Input Diode	(See OP240 for additional information)					
V _F	Forward Voltage OPB610, OPB620 OPB621	- 1.15	-	1.6 1.45	v v	I _F = 10 mA I _F = 10 mA
I _R	Reverse Current	-	-	100	μΑ	V _R = 3 V
Output Phot	totransistor (OPB610, OPB620) (See OP505 f	or addit	tional inf	ormatio	n)	
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	24	-	-	V	I _C = 100 μA
BV_{ECO}	Emitter-Collector Breakdown Voltage	0.4	-	-	V	I _{CE} = 100 μA
I _{CEO}	Collector-Emitter Dark Current	-	-	100	nA	V _{CE} = 5 V
Output Phot	todiode (OPB611, OPB621) (See OP999 for a	dditiona	al inform	ation)		
ID	Dark Current	-	-	65	nA	$V_{R} = 30 V, E_{E} = 0 mW$
V _{(BR)R}	Reverse Breakdown Voltage	60	-	-	V	IR = 100 μA, E _E = 0 mW
V _F	Forward Voltage	-	-	1.0	V	$I_F = 1 \text{ mA}, E_E = 0 \text{ mW}$
Combined						
V_{SAT}	Collector-Emitter Saturation Voltage OPB610, OPB620	-	-	0.4	v	I _F = 5 mA, I _C = 100 μA
		1		1		

Notes:

I_{C(ON)}

RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to leads when soldering. (1)

1

9

(2) Derate linearly 1.33 mW/°C above 25 ° C.

On-State Collector/Diode Current

OPB610, OPB620

OPB611, OPB621

Derate linearly 2.0 mW/°C above 25 ° C. (3) (4)

Plastic body is soluble in chlorinated hydrocarbons and keytones. It is recommended that a trial exposure to flux & cleaning chemicals is performed to ensure sensor is not damaged.

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 $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V} \text{ (gap unblocked)}$

 $V_{R} = 5 V$, $I_{F} = 20 mA$ (gap unblocked)

mΑ

μΑ

90

OPB610, OPB611, OPB620, OPB621



OPB610 - Flag Next to Emitter OPB610 - Flag Next to Sensor 1.20 1.20 Top to Bottom Top to Bottom 1.00 1.00 Normalized I_{c(0N} Response 090 090 090 Normalized I_{c(on} Response 0.80 Left to Right Right to Left Right to Left Left to Right 0.60 0.40 0.20 0.20 0.00 0.00 0.00 0.05 0.15 0.20 0.10 0.20 0.00 0.05 0.10 0.15 **Displacement Distance (inches) Displacement Distance (inches) OPB610 - Flag in Middle of Slot** 1.20 Top to Bottom Top to Bottom 1.00 0 Normalized I_{c(on)} Response 0.80 Right to Left Left to Right 0.60 Emitter Left to Right Right to Left 0.40 Sensor Width Ó 0.20 0.00

Performance

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0.10

Displacement Distance (inches)

0.15

0.20

0.05

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0.00

OPB610, OPB611, OPB620, OPB621



Performance



OPB620 - Flag in Middle of Slot





OPB620 - Flag Next to Sensor

Displacement Distance (inches)



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